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Question Paper Code: 37403

B.E. / B.Tech. DEGREE EXAMINATION, MAY 2018

Seventh Semester

Electronics and Communication Engineering

01UEC703 - MICROWAVE ENGINEERING

(Regulation 2013)

Duration: Three hours Maximum: 100 Marks

Answer ALL Questions

PART A - $(10 \times 2 = 20 \text{ Marks})$

- 1. Why isolators are called uniline?
- 2. Mention the reason for using S-matrix for microwave analysis.
- 3. What are the factors reducing efficiency of IMPATT diode?
- 4. Define negative resistance.
- 5. Why magnetron is called as cross filed device?
- 6. Compare TWTA and klystron amplifier.
- 7. Outline the features of coplanar strip line and microstrip line?
- 8. Write about diffusion and ion implantation process in fabrication.
- 9. List the different types of impedance measurement methods.
- 10. A wave guide termination with a VSWR of 1.5 is used to dissipate 150 watts of power. Determine the reflected power.

| (a) | Explain different types of waveguide junction with neat diagram. | (16) |
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| | Or | |
| (b) | Describe the scattering matrix of a directional coupler. | (16) |
| (a) | Explain the various modes of operation of Gunn oscillator with neat sketches. | (16) |
| | Or | |
| (b) | Derive the Manley Rowe power relations for the parametric amplifier. | (16) |
| (a) | Explain the velocity modulation process and derive the condition at which max bunching occurs in two cavity klystron. | imum (16) |
| | Or | |
| (b) | Describe with a neat sketch, the constructional details and principle of operation two cavity Klystron tube. Derive the expression for beam current and efficiency | |
| | | (16) |
| (a) | Discuss the various losses of microstrip line in detail and derive the q-fac microstrip lines. | tor of (16) |
| | Or | |
| (b) | (i) Specify the properties of materials that are required for the monolithic micro integrated circuits fabrication. | owave (8) |
| | (ii) Write short notes on coplanar strip lines and shielded strip lines. | (8) |
| (a) | Explain in detail the various impedance measurement techniques. | (16) |
| | Or | |
| (b) | Describe in detail with block diagram, the measurement of VSWR. | (16) |
| | (b)(a)(b)(a)(b) | (b) Describe the scattering matrix of a directional coupler. (a) Explain the various modes of operation of Gunn oscillator with neat sketches. Or (b) Derive the Manley Rowe power relations for the parametric amplifier. (a) Explain the velocity modulation process and derive the condition at which max bunching occurs in two cavity klystron. Or (b) Describe with a neat sketch, the constructional details and principle of operation two cavity Klystron tube. Derive the expression for beam current and efficiency microstrip lines. Or (b) (i) Specify the various losses of microstrip line in detail and derive the q-fact microstrip lines. Or (b) (i) Specify the properties of materials that are required for the monolithic microstrip are required circuits fabrication. (ii) Write short notes on coplanar strip lines and shielded strip lines. (a) Explain in detail the various impedance measurement techniques. |